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(54) Title: LIGHT EMITTING ARRAY

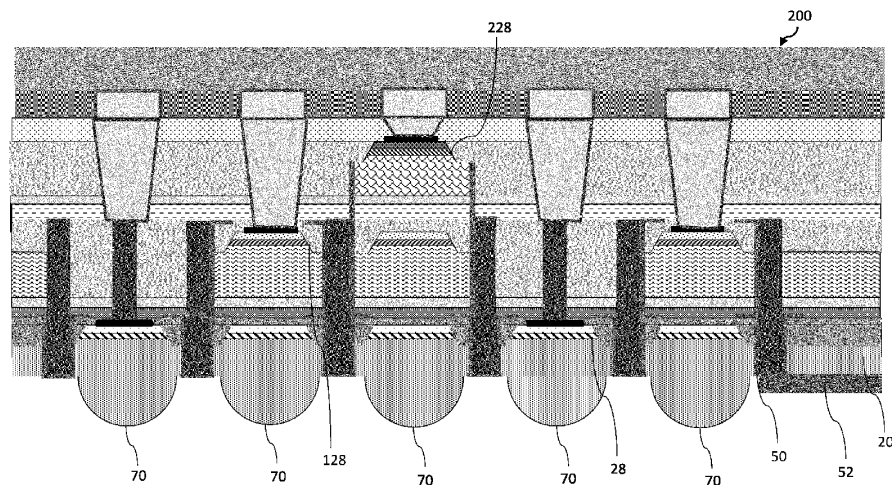


Figure 15

(57) **Abstract:** According to the first aspect of the disclosure, a method of forming a light emitting device array precursor is provided. The method comprises forming a first light emitting layer on a first substrate, forming an array of first light emitting devices from the first light emitting layer, each first light emitting device configured to emit light having a first wavelength. A first bonding layer is formed on the first light emitting layer. A second light emitting layer is formed on a second substrate, the second light emitting layer configured to emit light having a second wavelength different to the first wavelength. A second bonding layer is formed on the second light emitting layer. The second bonding layer is bonded to a handling substrate, followed by removing the second substrate from the second light emitting layer. A third bonding layer is formed on the second light emitting layer on an opposite side of the second light emitting layer to the handling layer. The first bonding layer is bonded to the third bonding layer and the handling substrate is removed

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from the second light emitting layer. An array of second light emitting devices is formed from the second light emitting layer, the array of second light emitting devices aligned relative to the array of first light emitting devices such that they are spaced apart from each other in a plane parallel to each of the first and second light emitting layers.